

D1FP3**30V 2A****特長**

- 小型SMD
- 超低 $V_F=0.4V$

Feature

- Small SMD
- Ultra-Low $V_F=0.4V$

用途

- バッテリー逆接防止
- DC出力OR用
- DC/DCコンバータ
- 携帯電話、パソコン

Main Use

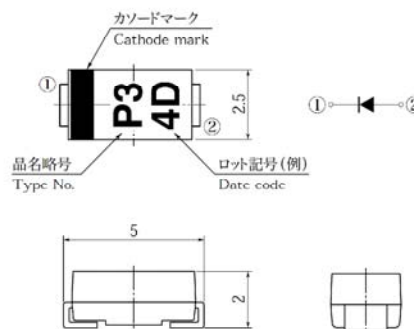
- Reverse connect protection for DC power source
- DC OR-output
- DC/DC Converter
- Mobile phone, PC

■外観図 OUTLINE

Package : 1F

Unit:mm

Weight 0.058g (Typ)



外形図については新電元Webサイト又は〈半導体製品一覧表〉をご参照下さい。捺印表示については捺印仕様をご確認下さい。

For details of the outline dimensions, refer to our web site or Semiconductor Short Form Catalog. As for the marking, refer to the specification "Marking, Terminal Connection".

■定格表 RATINGS**●絶対最大定格 Absolute Maximum Ratings (指定のない場合 $T_I = 25^\circ C$)**

項目 Item	記号 Symbol	条件 Conditions	品名 Type No.	D1FP3	単位 Unit
保存温度 Storage Temperature	T_{stg}			-55 ~ 125	$^\circ C$
接合部温度 Operation Junction Temperature	T_j			125	$^\circ C$
せん頭逆電圧 Maximum Reverse Voltage	V_{RM}			30	V
繰り返しせん頭サージ逆電圧 Repetitive Peak Surge Reverse Voltage	V_{RRSM}	パルス幅0.5ms, duty 1/40 Pulse width 0.5ms, duty 1/40		35	V
出力電流 Average Rectified Forward Current	I_o	50Hz 正弦波, 抵抗負荷, $T_I = 98^\circ C$ 50Hz sine wave, Resistance load, $T_I = 98^\circ C$		2	A
せん頭サージ順電流 Peak Surge Forward Current	I_{FSM}	50Hz 正弦波, 非繰り返し1サイクルせん頭値, $T_j = 25^\circ C$ 50Hz sine wave, Non-repetitive 1 cycle peak value, $T_j = 25^\circ C$		60	A

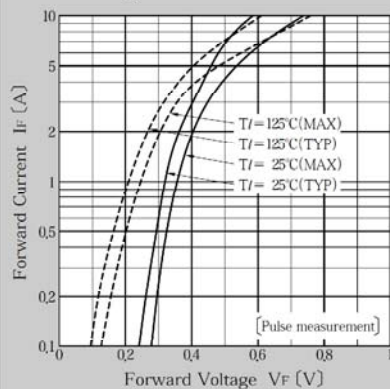
●電氣的・熱的特性 Electrical Characteristics (指定のない場合 $T_I = 25^\circ C$)

順電圧 Forward Voltage	V_F	$I_F = 0.8A$, パルス測定 Pulse measurement	MAX 0.35	V
		$I_F = 2A$, パルス測定 Pulse measurement	MAX 0.40	
逆電流 Reverse Current	I_R	$V_R = V_{RM}$, パルス測定 Pulse measurement	MAX 4.5	mA
接合容量 Junction Capacitance	C_j	$f = 1MHz$, $V_R = 10V$	TYP 130	pF
熱抵抗 Thermal Resistance	θ_{jl}	接合部・リード間 Junction to lead	MAX 23	$^\circ C/W$
	θ_{ja}	接合部・周囲間 Junction to ambient	MAX 108	
		アルミナ基板実装 On alumina substrate プリント基板実装 On glass-epoxy substrate	MAX 157	

■特性図 CHARACTERISTIC DIAGRAMS

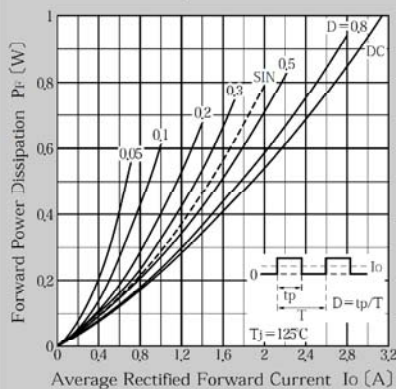
順方向特性

Forward Voltage



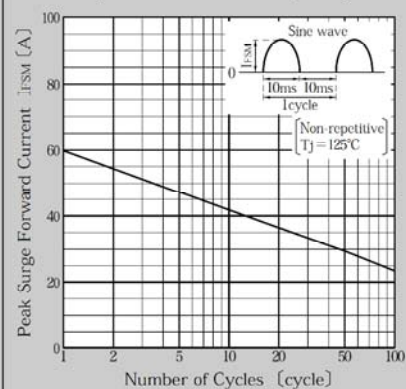
順電力損失曲線

Forward Power Dissipation



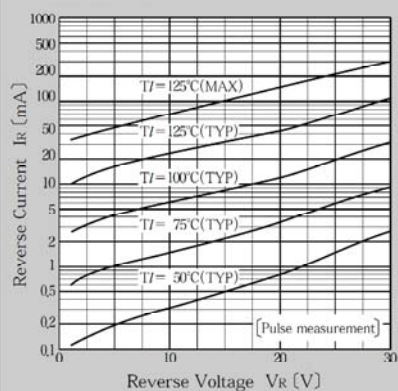
せん頭サージ順電流耐量

Peak Surge Forward Current Capability



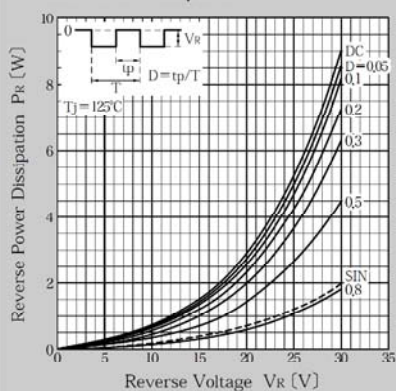
逆方向特性

Reverse Current



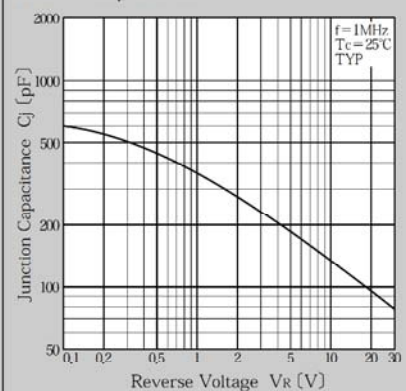
逆電力損失曲線

Reverse Power Dissipation



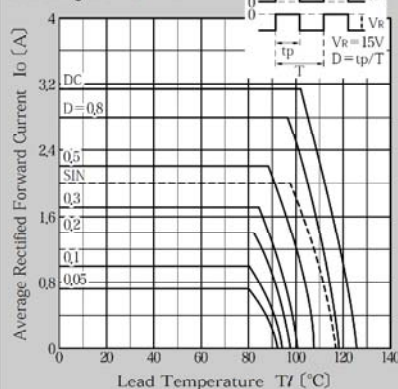
接合容量

Junction Capacitance



ディレーティングカーブ T_I-I_O

Derating Curve T_I-I_O



- * Sine waveは50Hzで測定しています。
- * 50Hz sine wave is used for measurements.
- * 半導体製品の特性は一般的にバラツキを持っています。
- * Typical is a statistical average of the device's ability.
- * Semiconductor products generally have characteristic variation.
- * Typical is a statistical average of the device's ability.

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Website :

Welcome to visit www.ameya360.com

Contact Us :

➤ Address :

401 Building No.5, JiuGe Business Center, Lane 2301, Yishan Rd
Minhang District, Shanghai , China

➤ Sales :

Direct +86 (21) 6401-6692

Email amall@ameya360.com

QQ 800077892

Skype ameyasales1 ameyasales2

➤ Customer Service :

Email service@ameya360.com

➤ Partnership :

Tel +86 (21) 64016692-8333

Email mkt@ameya360.com